

MBRF1045

Technical Data Data Sheet N0819, Rev. B



MBRF1045 SCHOTTKY RECTIFIER



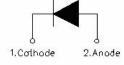
Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Circuit Diagram



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=80°C, rectangular wave form	10	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	150	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@10A, Pulse, TJ = 25 ℃	0.56	0.65	V
	V _{F2}	@10A, Pulse, T _J = 125 ℃	0.54	0.55	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 ℃	0.03	1.0	mA
	I _{R2}	@V _R = rated V _R T _J = 125 ℃	8	15	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	260	400	pF
Typical Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 μs, duty cycle < 2%

- China Germany Korea Singapore United States •
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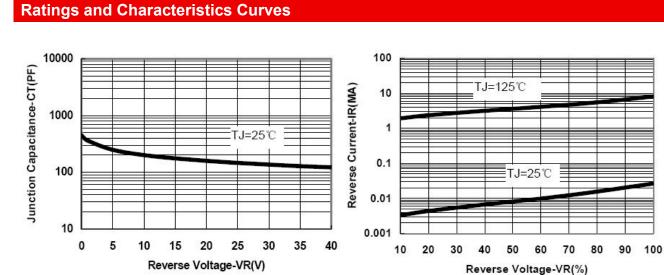
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RoHS 🗭

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +150	°C	
Storage Temperature	T _{stg}	-	-55 to +150	°C	
Typical Thermal Resistance Junction to Case	Rejc	DC operation	2.0	°C/W	
Approximate Weight	wt	-	1.6	g	
Case Style	ITO-220AC				



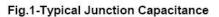
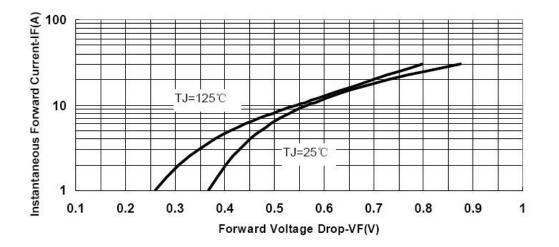


Fig.2-Typical Reverse Characteristics





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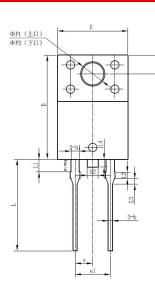


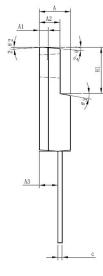
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Mechanical Dimensions ITO-220AC

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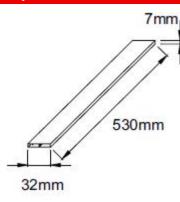




SYMBOL	Millimeters				
STNBOL	MIN.	TYP.	MAX.		
A	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
с	0.55	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
e	-	2.55	-		
e1	-	5.10	-		
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
L4	-	1.10	1.50		
ΦΡ1 (上口)	3.30	3.50	3.70		
ΦΡ2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			



Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MBR

F

10

45

SSG YY

WW

L

- = Device Type
- = Package type = Forward Current (10A)
- = Reverse Voltage (45V)
- = SSG

= Year

= Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping		
MBRF1045	ITO-220AC (Pb-Free)	50 pcs/ tube		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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